

Application Note No. 030

A 1.9 GHz Low Noise Amplifier board using
Si-MMIC BGA427

Small Signal Discretes



Never stop thinking

Edition 2007-01-09

**Published by
Infineon Technologies AG
81726 München, Germany**

**© Infineon Technologies AG 2007.
All Rights Reserved.**

LEGAL DISCLAIMER

THE INFORMATION GIVEN IN THIS APPLICATION NOTE IS GIVEN AS A HINT FOR THE IMPLEMENTATION OF THE INFINEON TECHNOLOGIES COMPONENT ONLY AND SHALL NOT BE REGARDED AS ANY DESCRIPTION OR WARRANTY OF A CERTAIN FUNCTIONALITY, CONDITION OR QUALITY OF THE INFINEON TECHNOLOGIES COMPONENT. THE RECIPIENT OF THIS APPLICATION NOTE MUST VERIFY ANY FUNCTION DESCRIBED HEREIN IN THE REAL APPLICATION. INFINEON TECHNOLOGIES HEREBY DISCLAIMS ANY AND ALL WARRANTIES AND LIABILITIES OF ANY KIND (INCLUDING WITHOUT LIMITATION WARRANTIES OF NON-INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHTS OF ANY THIRD PARTY) WITH RESPECT TO ANY AND ALL INFORMATION GIVEN IN THIS APPLICATION NOTE.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

Application Note No. 030

Revision History: 2007-01-09, Rev. 2.0

Previous Version: 2000-07-28

Page	Subjects (major changes since last revision)

1 A 1.9 GHz Low Noise Amplifier board using Si-MMIC BGA427

This application note provides general information PCB layout and list of components, circuit diagram and measured data of a BGA427-amplifier board.

Data at 1.9 GHz

Biassing	3 V (9.5 mA)	5 V (18 mA)
Gain $ S_{21} ^2$ [dB]	18	19.5
Noise Figure NF [dB]	2.25	2.45
Intercept point output IP3out [dBm]	7	15
Return loss in/out	>10	>10
Reverse isolation [dB]	22	22

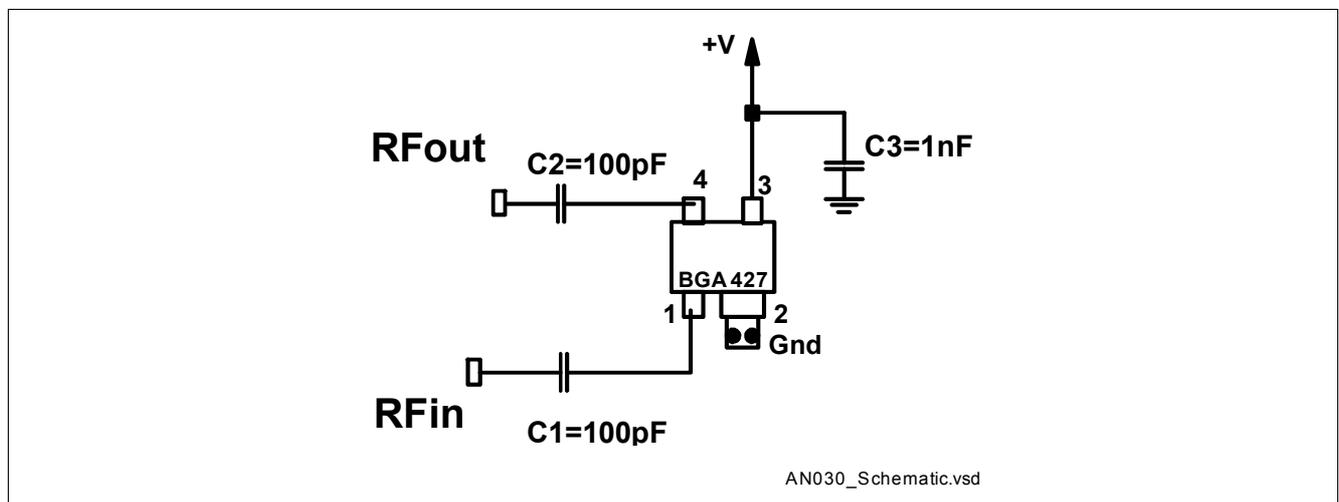


Figure 1 Schematic Diagram

- The measured data and diagrams include losses of SMA-connectors and the relatively high loss of the microstrip lines on the epoxy-board.
- The use of plated through holes right at the device (Gnd) is essential. Thin PC-boards are recommended to minimize the parasitic inductance to ground.
- An RF decoupling capacitor e.g. 100 pF (size 0603 or 0805) should be mounted as close as possible to the device (pin 3) for optimum performance. In addition, a larger value capacitor should be connected from Pin 3 to ground to provide a low impedance path for lower frequencies. The use of good quality dielectric capacitors is recommended (e.g. COG types) to ensure stable operation.

A 1.9 GHz Low Noise Amplifier board using Si-MMIC BGA427

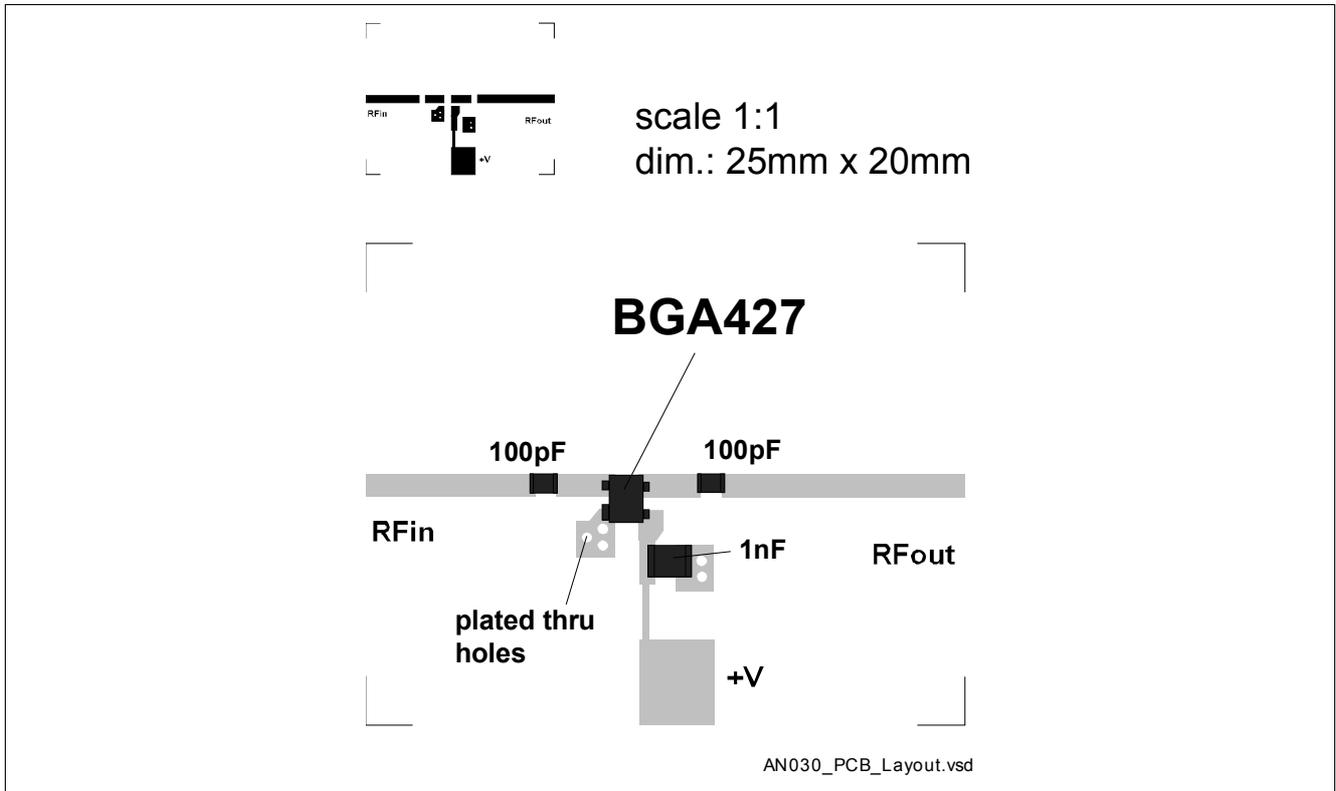


Figure 2 PCB Layout and Component Placement

Table 1 Bill of Material

Component	Value	Unit	Size	Comment
C1	100	pF	0603/0805	DC-block
C2	100	pF	0603/0805	DC-block
C3	1	nF	0603/0805	RF-short
Si-MMIC				Si_MMIC BGA427
Substrate	FR4			$h = 0.5 \text{ mm}$, $\epsilon_r = 4.5$

A 1.9 GHz Low Noise Amplifier board using Si-MMIC BGA427

Measured data

+V = 3 Vdc / I = 9.5 mA

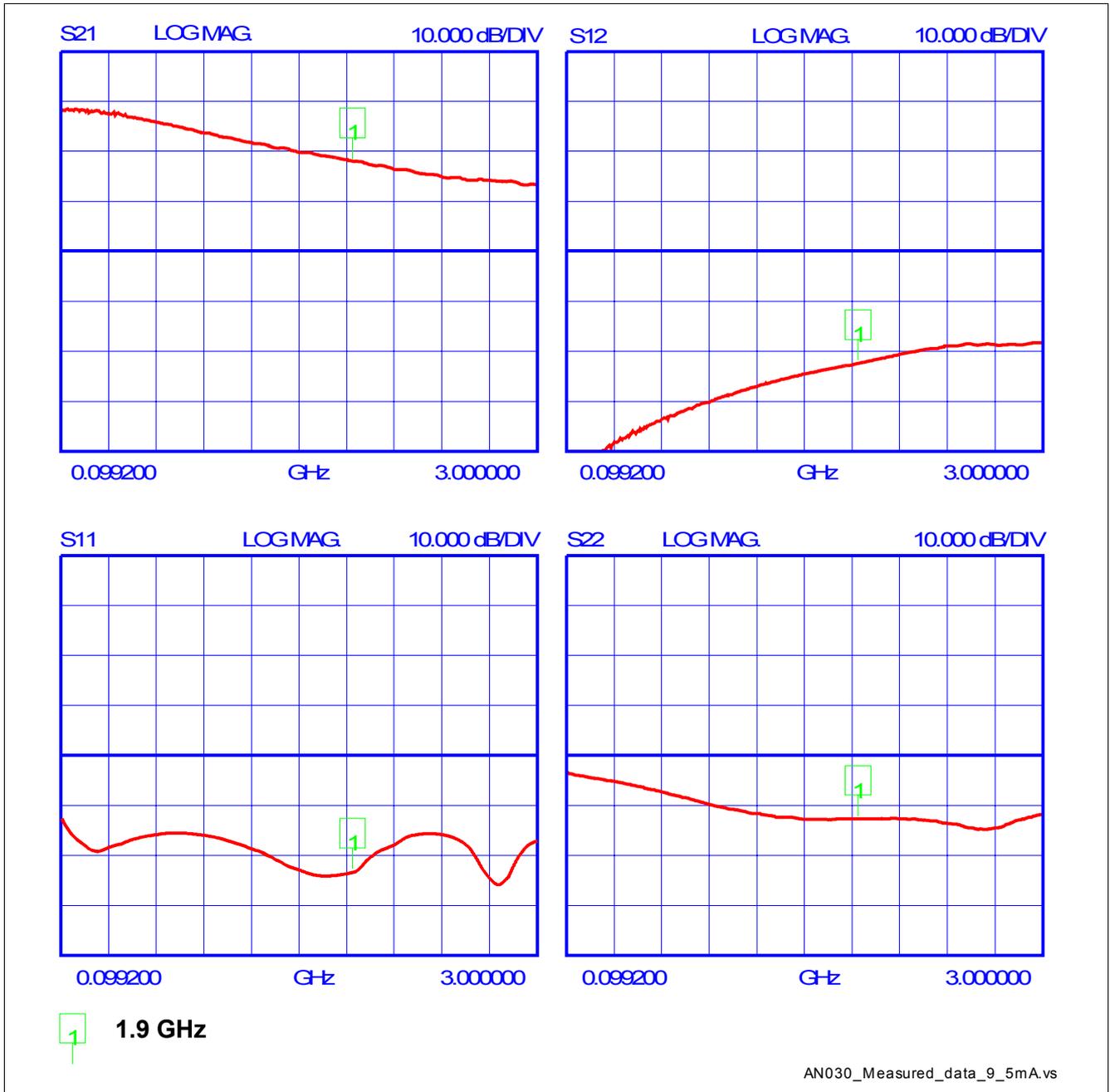


Figure 3 Measured data

A 1.9 GHz Low Noise Amplifier board using Si-MMIC BGA427

Measured data

+V = 3 Vdc (I = typ. 18 mA)

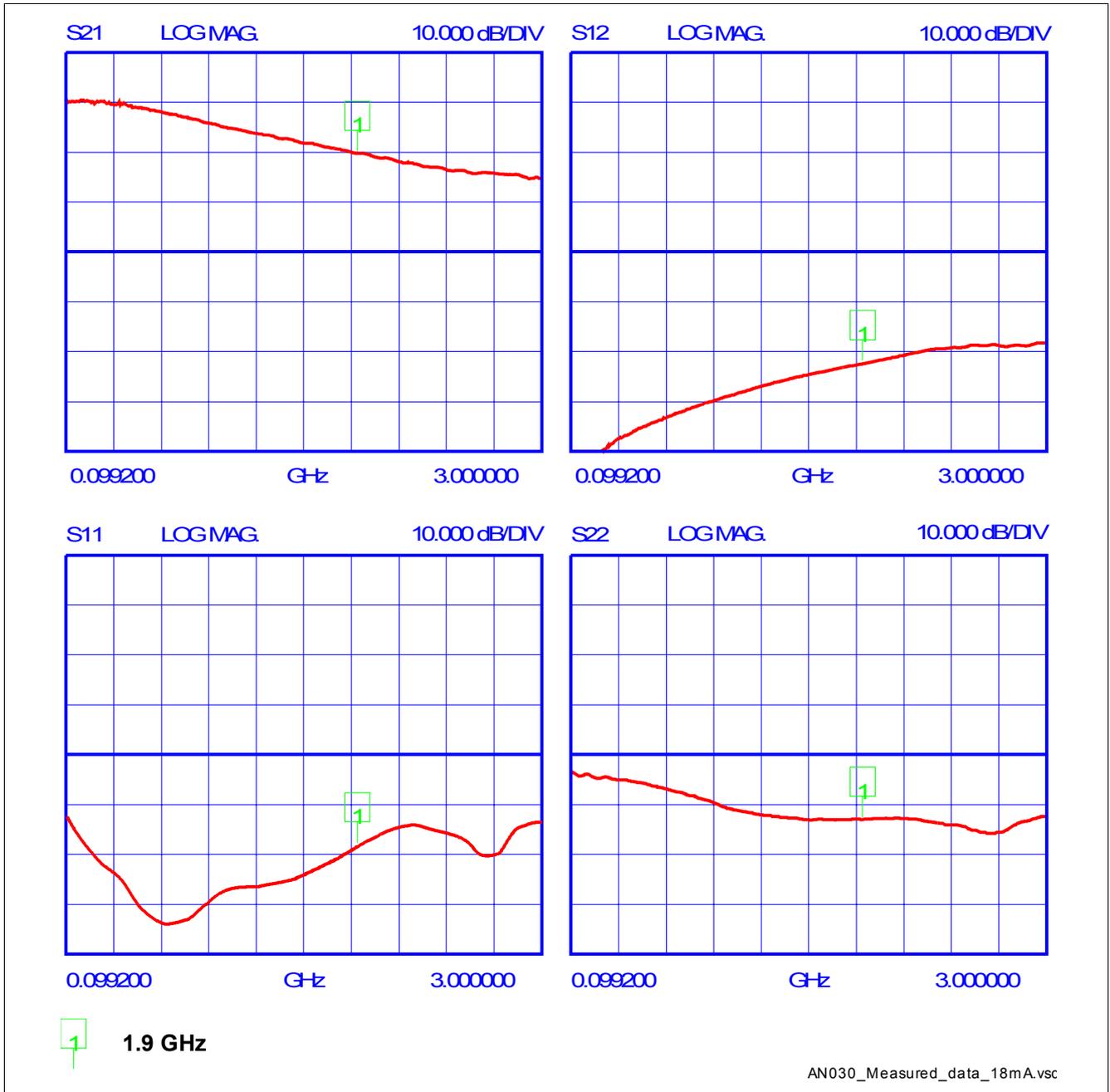


Figure 4 Measured data